NSN 5961-01-349-0240

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-349-0240 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.225 inches **Terminal Length:** Between 1.000 inches and 1.300 inches **Overall Diameter:** Between 0.065 inches and 0.110 inches **Function For Which Designed:** Rectifier **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, instantaneous and 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense supply center columbus production standard no lo4429; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead **Reference Number Differentiating Characteristics:** Breference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp. Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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